

Description

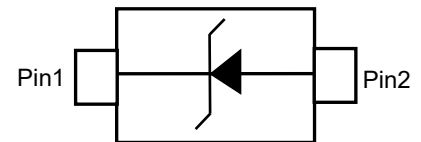
The SXESD3H5VU transient voltage suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The SXESD3H5VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The SXESD3H5VU is available in a SOD-323 package with working voltages of 5 volt.



SOD-323(Top View)

Feature

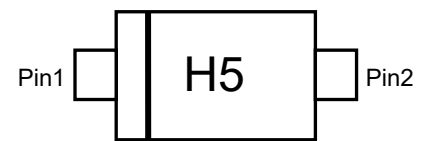
- 1400W Peak pulse power per line ($t_p = 8/20\mu s$)
- SOD-323 package
- Response time is typically < 1 ns
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) $\pm 30KV$ (air), $\pm 30KV$ (contact); IEC 61000-4-4 (EFT) 40A (5/50ns)



Circuit Diagram

Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players



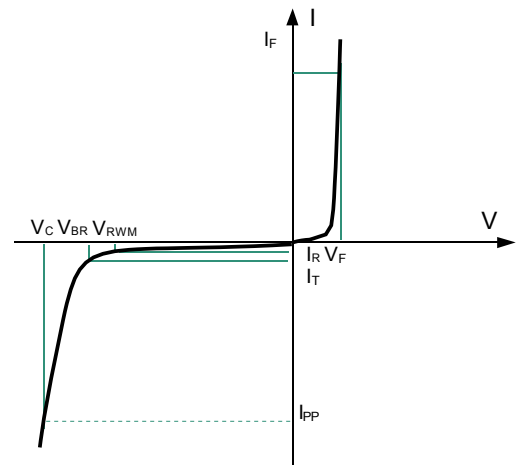
Marking (Top View)

Mechanical Characteristics

- Lead finish: 100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature: $260^{\circ}C$
- Pure tin plating: 7 ~ 17 μm
- Pin flatness: ≤ 3 mil

Electronics Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				5	V
Breakdown Voltage	V_{BR}	$I_t = 1\text{mA}$	6	7	7.8	V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$			2	μA
Clamping Voltage	V_C	$I_{PP} = 40\text{A}$ $t_P = 8/20\mu\text{s}$		10.5	11.5	V
Clamping Voltage	V_C	$I_{PP} = 100\text{A}$ $t_P = 8/20\mu\text{s}$		14.5	15.5	V
Junction Capacitance	C_j	$V_R = 0\text{V}$ $f = 1\text{MHz}$	900	990	1050	pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power ($t_P = 8/20\mu\text{s}$)	P_{PP}	1400	W
Lead Soldering Temperature	T_L	260 (10 sec)	°C
Operating Temperature	T_J	-55 to +150	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Typical Characteristics

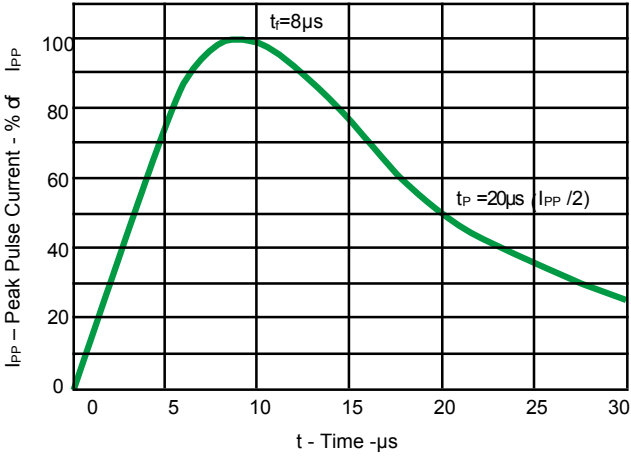


Fig 1. Pulse Waveform

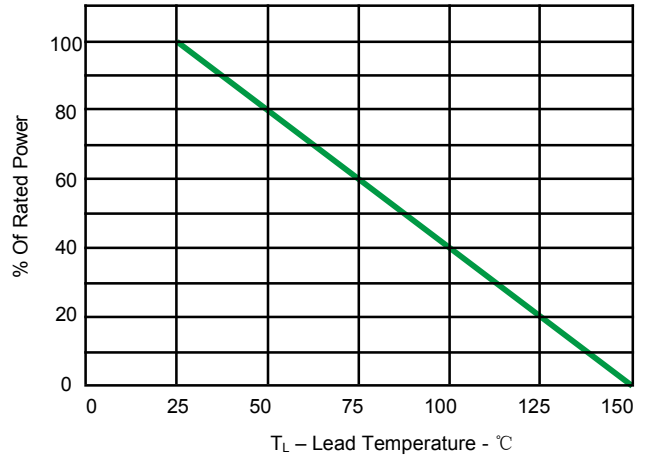


Fig 2. Power Derating Curve

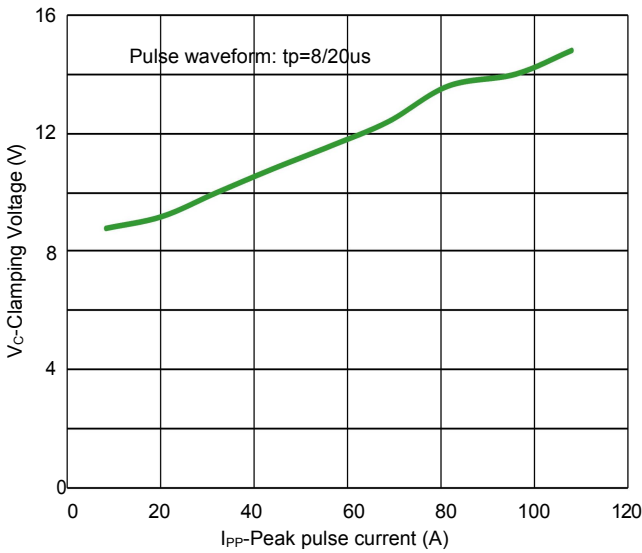


Fig 3. Clamping voltage vs. Peak pulse current

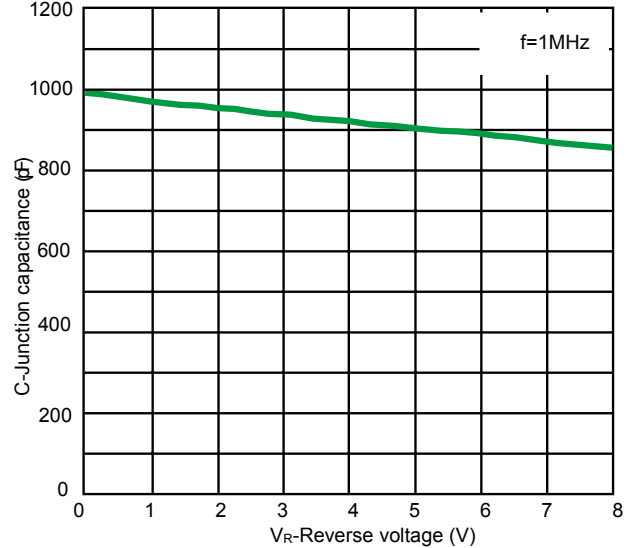


Fig 4. Capacitance vs. Reverse voltage

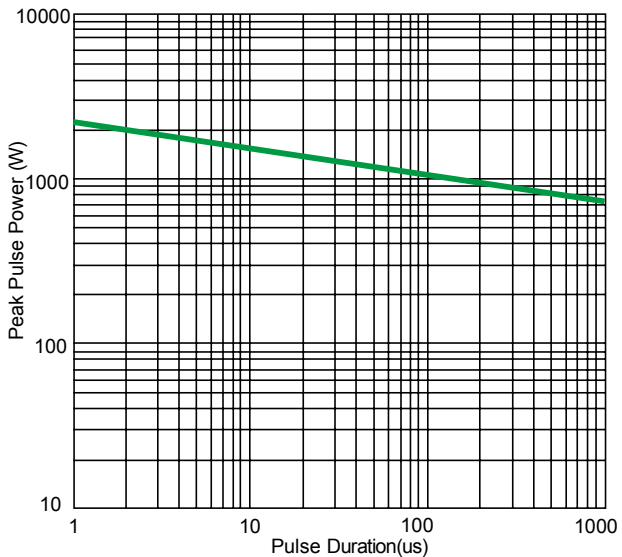
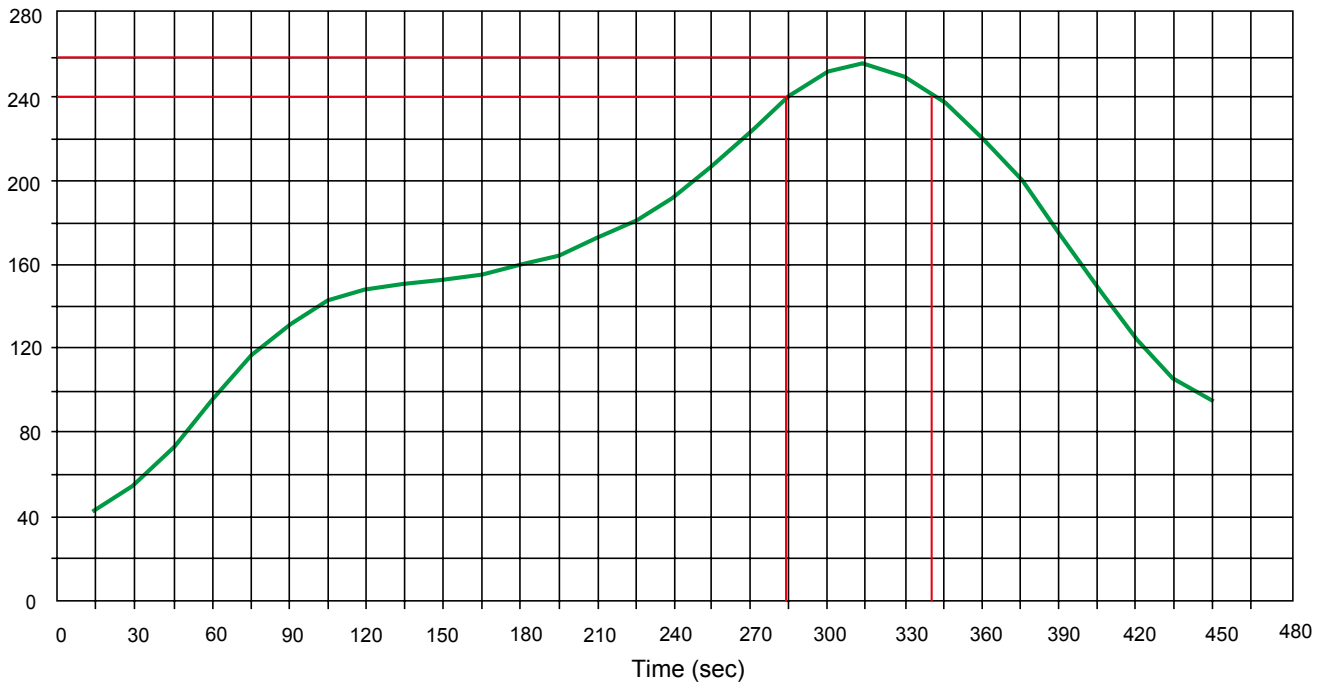


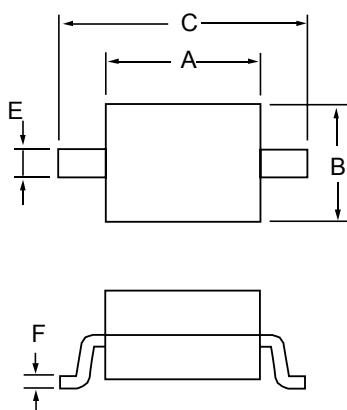
Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

Solder Reflow Recommendation

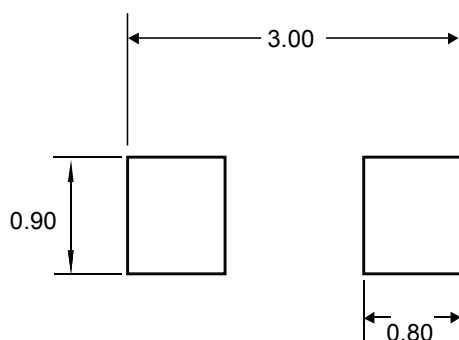
Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec



Product dimension (SOD-323)



Dim	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.063	0.075	1.60	1.90
B	0.045	0.057	1.15	1.45
C	0.090	0.106	2.30	2.70
D	0.031	0.043	0.80	1.00
E	0.010	0.01	0.25	0.40
F	0.004	0.007	0.09	0.18
H	0.000	0.004	0.00	0.10



Suggested PCB Layout

Unit:mm

Ordering information

Device	Package	Reel	Shipping
SXESD3H5VU	SOD-323 (Pb-Free)	7"	3000 / Tape & Reel